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The SCAN+*U* method in the investigation of complex transition metal oxides: a case study on YSr₂Cu₂FeO_{7+δ} (δ = 0, 1)

Marianela Gómez-Toledo  and Elena M. Arroyo-de Dompablo *

Assessment of DFT methods is essential to sustain reliability in the computational investigation of complex transition metal oxides. This work evaluates the performance of the strongly constrained and appropriately normed (SCAN) functional and its extended Hubbard-*U* methodology (SCAN+*U*) to model the YSr₂Cu₂FeO_{7+δ} (0 < δ < 1) perovskite-based system. The influence of the individual *U*_{Cu} and *U*_{Fe} Hubbard parameters (0 < *U* < 4 eV) on the calculated electronic, magnetic and crystal structures of the end members δ = 1 (metallic) and δ = 0 (insulating) is analyzed. The introduction of the *U*-correction terms enhances the reproduction of the crystal structures, with a *U*_{Cu} value of 1 eV improving the band gap accuracy for the YSr₂Cu₂FeO₇ phase, while maintaining the metallic characteristics of YSr₂Cu₂FeO₈. At a fixed *U*_{Cu} value, the results are almost insensitive to the *U*_{Fe} value used in the calculations. The findings emphasize that for oxides containing several TM ions, the optimal *U*_{TM} values may differ from those of the simple TM oxides.

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Introduction

Transition metal (TM) oxides are one of the most interesting classes of solids, exhibiting excellent properties and applications in a wide variety of fields. Methods based on density functional theory (DFT) play a central role in designing advanced functional oxides. They enable the identification of promising materials through property prediction and facilitate the understanding of the underlying structure–composition–property relationships. A current challenge is selecting a DFT methodology capable of modelling complex TM oxides with strongly interacting d-electrons. The GGA + *U* method has been extensively used in the last few decades; to the GGA exchange–correlation functional, a TM-specific Hubbard *U* parameter is added describing the on-site Coulomb interaction between localized electrons. However, progress in the modelling of correlated TM oxides requires testing and evaluating advanced exchange–correlation functionals.

The recently developed strongly constrained and appropriately normed (SCAN) meta-GGA functional¹ has demonstrated a superior performance in reproducing the fundamental physical properties and phenomena associated with correlated oxides.^{2–8} Furthermore, studies have shown that incorporating the SCAN functional into the DFT+*U* framework (SCAN+*U*) can enhance the accuracy in reproducing certain physical

properties of transition metal oxides.^{9–13} For example, Carter and coworkers demonstrated that the introduction of the Hubbard term improves the reproduction of the ground-state properties of binary 3d TM oxides, being critical for the prediction of the most stable polymorphs of Mn₂O₃ and Fe₃O₄.^{9,10} The SCAN+*U* method has also been used to evaluate the formation energy of anion vacancies, which are highly involved in properties related to energy applications, of ABO₃ perovskites with various A and B (TM) elements and diverse electronic structures.¹¹ For BiFeO₃ polymorphs, the effect of Fe-site doping on the phase stability, as well as on the structural and ferroelectric properties, has been assessed.¹² For oxides containing two TM ions, double Nb-perovskites (Sr₂SmNbO₆, Sr₂CoNbO₆ and Ba₂CoNbO₆) have been investigated,¹⁴ although the authors dropped the treatment of correlation in Nb to simplify the analysis.

Assessing the performance of the SCAN+*U* method in modelling complex transition metal oxides represents a crucial step forward in the predictive design of functional oxides, especially defying for oxides containing different TM ions. This study focuses on the SCAN+*U* method in the investigation of complex oxides YSr₂Cu₂FeO_{7+δ}, for which the SCAN functional correctly captures the metal-to-insulating transition as a function of the oxygen content.⁸ The perovskite-related crystal structure of the YSr₂Cu₂FeO_{7+δ} system (Fig. 1) can be referred to the YBaCuO-type structure with the replacement of one layer of Cu atoms with Fe.^{15,16} The YSr₂Cu₂FeO₈ (δ = 1) idealized compound, with [FeO₆] octahedral units in the FeO₂ layers (Fig. 1a), is a metallic

Departamento de Química Inorgánica, Universidad Complutense de Madrid,
28040 Madrid, Spain. E-mail: e.arroyo@quim.ucm.es



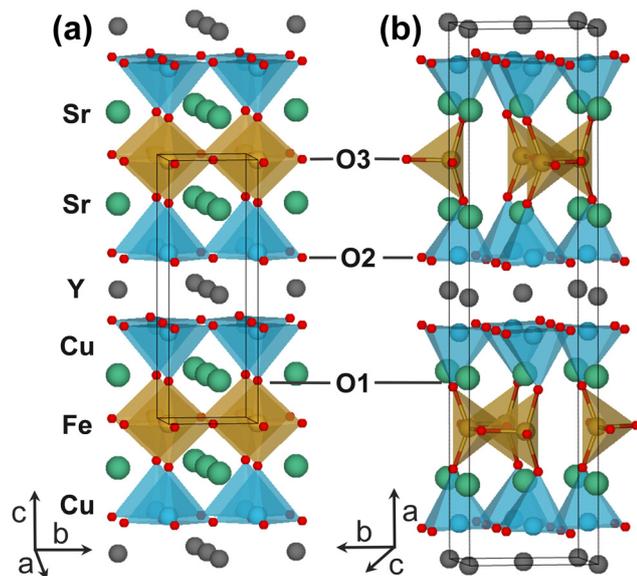


Fig. 1 Crystal structures of the idealized models of $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ stoichiometric oxides: (a) $\text{YSr}_2\text{Cu}_2\text{FeO}_8$ (S.G. $P4/mmm$) and (b) $\text{YSr}_2\text{Cu}_2\text{FeO}_7$ (S.G. $Ima2$). Color code: Fe in brown, Cu in blue, Sr in green, Y in grey and O in red.

oxide with a superconducting transition at a T_c of 70 K.¹⁷ Lowering the oxygen content creates vacancies in the O3 positions of the $\text{FeO}_{1+\delta}$ layer, which leads to a tetrahedral coordination for all Fe atoms in the idealized $\text{YSr}_2\text{Cu}_2\text{FeO}_7$ ($\delta = 0$) compound (Fig. 1b). The synthesized compounds with $\delta \sim 0$ are insulators with mainly Fe^{3+} and Cu^{2+} ions.^{8,16,18,19}

The combination of Cu and Fe ions in different oxidation states, and the evolution of the electronic properties of the $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ series, provides an excellent framework to examine the applicability of the SCAN+ U approach in the DFT investigation of complex oxides. This study delves into the effects of U_{Cu} and U_{Fe} correction terms on the crystallographic, magnetic and electronic structures of the idealized end-members of $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ ($\delta = 0$ and 1). By conducting calculations with individual U terms ranging from 0 to 4 eV, we determine and discuss the appropriate set of U values for accurately describing the system. A relevant question arises regarding the transferability of U_{TM} parameters from simple oxides to their combinations in complex TM oxides. We will demonstrate that such transferability cannot be guaranteed.

Methodology

Calculations for the ideal stoichiometric end-members of the $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ family, $\text{YSr}_2\text{Cu}_2\text{FeO}_8$ and $\text{YSr}_2\text{Cu}_2\text{FeO}_7$, have been performed using the *ab initio* total energy and molecular dynamics program VASP (Vienna Ab initio Simulation Package) developed at the Universität Wien.^{20,21} The interaction of core electrons with the nuclei is described using the projector augmented wave (PAW) method²² with $2s^22p^4$ of O, $3s^23p^63d^74s^1$ of Fe, $3p^63d^{10}4p^1$ of Cu, $4s^24p^65s^2$ of Sr, and $4s^24p^64d^15s^2$ of Y being treated as valence electrons. The energy cut-off for the

plane wave basis set was fixed at a constant value of 600 eV throughout the calculations. The integration in the Brillouin zone was done on appropriate k -point sets determined by the Monkhorst–Pack scheme. The k -point meshes were set at $2 \times 8 \times 8$ for $\text{YSr}_2\text{Cu}_2\text{FeO}_7$ and $10 \times 10 \times 4$ for $\text{YSr}_2\text{Cu}_2\text{FeO}_8$, using a Gaussian smearing parameter of 0.05 eV. For the density of states (DOS) calculations, the tetrahedron method with Bloch corrections²³ was used. Self-consistency was achieved with a tolerance in total energy of 1×10^{-4} eV for geometry optimization and 1×10^{-6} eV for DOS calculations.

A local Hubbard- U (SCAN+ U) was added to Fe and Cu atoms, following the simplified rotationally invariant framework developed by Dudarev *et al.*²⁴ Typically, U is formulated as $U_{\text{eff}} = U - J$, where U is the onsite Coulomb term and J is the exchange term. In this work, this effective parameter is simply referred as U . The J value was fixed to 1 eV. Effective U values between 0 and 4 eV were used for the 3d orbitals of Cu and Fe. It should be noted that a value of 4 eV for Fe and Cu was found appropriate in GGA + U investigations.^{25–27} The local magnetic moments were taken from the difference between the projected electron density of up and down spins onto a 1 Å ionic radius sphere. Bader charge analysis²⁸ was performed on the charge density files²⁹ using the pymatgen package.³⁰

The crystallographic models of $\text{YSr}_2\text{Cu}_2\text{FeO}_8$ and $\text{YSr}_2\text{Cu}_2\text{FeO}_7$ were, respectively, constructed taking the initial positions from $\text{YSr}_2\text{Cu}_2\text{FeO}_{7.86}$ (ICSD file 11514)¹⁷ and $\text{YSr}_2\text{Cu}_2\text{GaO}_7$ (ICSD file 71263).³¹ For the metallic $\text{YSr}_2\text{Cu}_2\text{FeO}_{7.86}$, López *et al.*¹⁷ found a magnetic structure consisting of in-plane FM coupling within the $\text{FeO}_{1+\delta}$ layers and a weak AFM coupling between layers along the c -axis (A-type AFM ordering). Due to the soft character of the inter-plane magnetic interactions ($T_N \sim 20 \text{ K}^32$), subsequent DFT calculations utilized a ferromagnetic (FM) structure to model the idealized $\text{YSr}_2\text{Cu}_2\text{FeO}_8$,⁸ which is also employed in the present study. Investigation of the idealized $\text{YSr}_2\text{Cu}_2\text{FeO}_7$ is carried out in the antiferromagnetic ground state (C-type AFM) and the metastable ferromagnetic structure (FM). Additional SCAN+ U calculations have been conducted with the maximum U values tested ($U_{\text{Cu}} = U_{\text{Fe}} = 4 \text{ eV}$) using the A-type AFM magnetic ordering for $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ with $\delta = 0$ and 1. More details of magnetic structures are given in ref. 8.

Results

The experimental lattice parameters and bond distances of $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ ($\delta = 0,1$) crystal structures are reproduced well using both SCAN and SCAN+ U methods, with errors below 3%. For conciseness, Table 1 lists only the values for SCAN+ U with the highest U values tested, 4 eV for Fe and Cu. Noteworthy, introducing the U correction term reduces the discrepancies between the theory and experimental structural data. For instance, within the SCAN+ U approach, the calculated unit cell volumes (errors of 0.9% and 0.7% for $\text{YSr}_2\text{Cu}_2\text{FeO}_8$ and $\text{YSr}_2\text{Cu}_2\text{FeO}_7$, respectively) are closer to the experimental values than those within the SCAN approach (errors of 2% and 1.2% for $\text{YSr}_2\text{Cu}_2\text{FeO}_8$ and $\text{YSr}_2\text{Cu}_2\text{FeO}_7$, respectively). Since the



Table 1 Calculated unit cell parameters (Å), unit cell volumes (Å³), volume per atom (Å³) and selected bond lengths (Å) for the YSr₂Cu₂FeO₇ and YSr₂Cu₂FeO₈ idealized oxides. The experimental data of YSr₂Cu₂FeO_{7.86} (ICSD-11514⁴⁷) and YSr₂Cu₂FeO_{7.12} (ICSD-151654⁴⁹) are included for comparison. Within the SCAN+*U* method *U* = 4 eV is used for Cu and Fe

YSr ₂ FeCu ₂ O ₈	Experimental	SCAN	SCAN+ <i>U</i>	YSr ₂ FeCu ₂ O ₇	Experimental	SCAN AFM-C	SCAN+ <i>U</i> AFM-C	SCAN FM	SCAN+ <i>U</i> FM
<i>a</i>	3.8145(3)	3.7861	3.7989	<i>a</i>	22.9241(8)	22.8529	22.8568	22.9157	22.8640
<i>c</i>	11.327(7)	11.2755	11.3116	<i>b</i>	5.4584(2)	5.4411	5.4536	5.4365	5.4646
<i>V</i>	164.81(1)	161.62	163.26	<i>c</i>	5.4080(2)	5.3744	5.3893	5.3608	5.3956
<i>V</i> per atom	11.77	11.54	11.66	<i>V</i>	676.70	668.22	671.79	675.96	674.14
d Fe–O3	1.9072(2)	1.8930	1.8994	<i>V</i> per atom	12.89	12.85	12.91	13.00	12.96
d Fe–O1	1.8434(4)	1.8417	1.8591	Mean d Fe–O	1.8757	1.8732	1.8888	1.8880	1.8987
d Fe–O1/d Fe–O3	0.9663	0.9729	0.9788	Fe–O3–Fe	125.5°	124.5°	123.2°	120.1°	121.0°
d Cu–O2	1.9244(4)	1.9147	1.9232	Mean d Cu–O2	1.9335	1.9237	1.9368	1.9207	1.9366
d Cu–O1	2.117(4)	2.0812	2.0738	d Cu–O1	2.312(4)	2.3449	2.3210	2.3600	2.3071
d Cu–O1/d Cu–O2	1.1000	1.0870	1.0783	d Cu–O1/d Cu–O2	1.1958	1.2148	1.2019	1.2288	1.1913
d Cu–Cu	3.407(4)	3.4297	3.4459	d Cu–Cu	3.338(0)	3.3095	3.3379	3.3119	3.3676
d Cu–Fe	3.960(3)	3.9229	3.9329	d Cu–Fe	4.085(8)	4.0815	4.0681	4.0946	4.0543

Cu-3d states play a critical role in the metal-to-insulating transition in high-*T_c* cuprate superconductors,³³ the Cu–O distances are analyzed in detail. Fig. 2 shows the calculated Cu–O1 (apical oxygen) and Cu–O2 (equatorial oxygen) distances as a function of the *U_{Cu}* and *U_{Fe}* values. The results show that, for both YSr₂Cu₂FeO₈ and YSr₂Cu₂FeO₇, increasing *U_{Cu}* results in a better agreement with the experimental available values. It can be seen in Fig. 2a that, for the metallic phase YSr₂Cu₂FeO₈, at a fixed *U_{Cu}*, applying *U_{Fe}* produces a decrease in d Cu–O1 (a maximum variation of 4% for *U_{Cu}* = 0) and a subtle increase in d Cu–O2 (a maximum variation of 0.7% at *U_{Cu}* = 0). On the other hand, for the C-type AFM-YSr₂Cu₂FeO₇, the Cu–O distance depends mostly on *U_{Cu}*. Hence, at a fixed *U_{Cu}*, changing *U_{Fe}* has little to no effect on the Cu–O bonding distances.

For the sake of completeness, Fig. 2 incorporates data from a preceding PBE and PBE+*U* (*U_{Cu}* = *U_{Fe}* = 4 eV) investigation.⁸ As previously discussed, the PBE functional tends to yield larger bonding lengths than the SCAN functional. Specifically, the Cu–O1 distance in the YSr₂Cu₂FeO₇ oxide exhibits the most significant deviation from experimental values (5.7%).

Introducing the *U* parameter to the PBE method results in changes in the Cu–O bond distances, with d Cu–O1 for $\delta = 0$ decreasing and the others increasing, following the same trends observed with SCAN+*U*.

Regarding the electronic properties of YSr₂Cu₂FeO₈, the SCAN functional correctly reproduces the itinerant electron character and metallic behavior of the oxide (calculated DOS in Fig. 3a). Applying the Hubbard correction (SCAN+*U*) produces a downshift of the occupied Fe/Cu-3d states, keeping the 3d orbitals atomic-like and diminishing their hybridization with the 2p-oxygen (less covalent TM–O bonding). This is clearly observed in Fig. 3a for the case with *U_{Cu}* and *U_{Fe}* = 4 eV. Moreover, since *U* penalizes the fractional occupation on metal ions, the electrons tend to localize in the majority spin in Cu-3d and Fe-3d orbitals and a band gap opens in the minority spin channel, resulting in a half-metal compound. Fig. 3b shows the dependence of the down-spin band gap with the *U_{Cu}* and *U_{Fe}* values employed in the SCAN+*U* calculations. Half-metallicity is largely influenced by the *U* value used for the Cu-3d states. When *U_{Cu}* < 1.0 eV, independent of the *U_{Fe}* tested

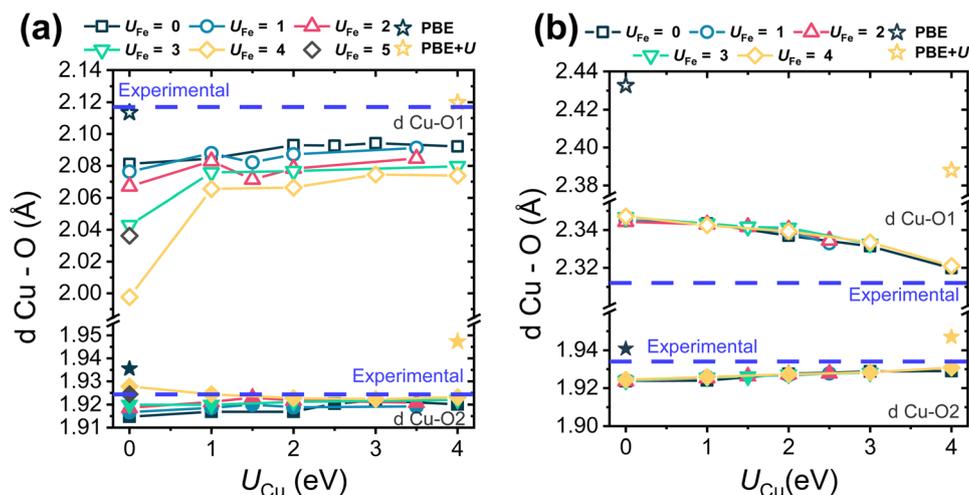


Fig. 2 Calculated Cu–O bond lengths (Å) within the SCAN+*U* approach as a function of *U_{Cu}* and *U_{Fe}* values for (a) YSr₂Cu₂FeO₈ and (b) YSr₂Cu₂FeO₇ idealized oxides. The experimental bond lengths are depicted as dashed blue lines. The PBE (*U_{Fe}* and *U_{Cu}* = 0 eV) and PBE+*U* (*U_{Fe}* and *U_{Cu}* = 4 eV) results from a previous investigation⁸ are denoted by blue and yellow asterisks, respectively.



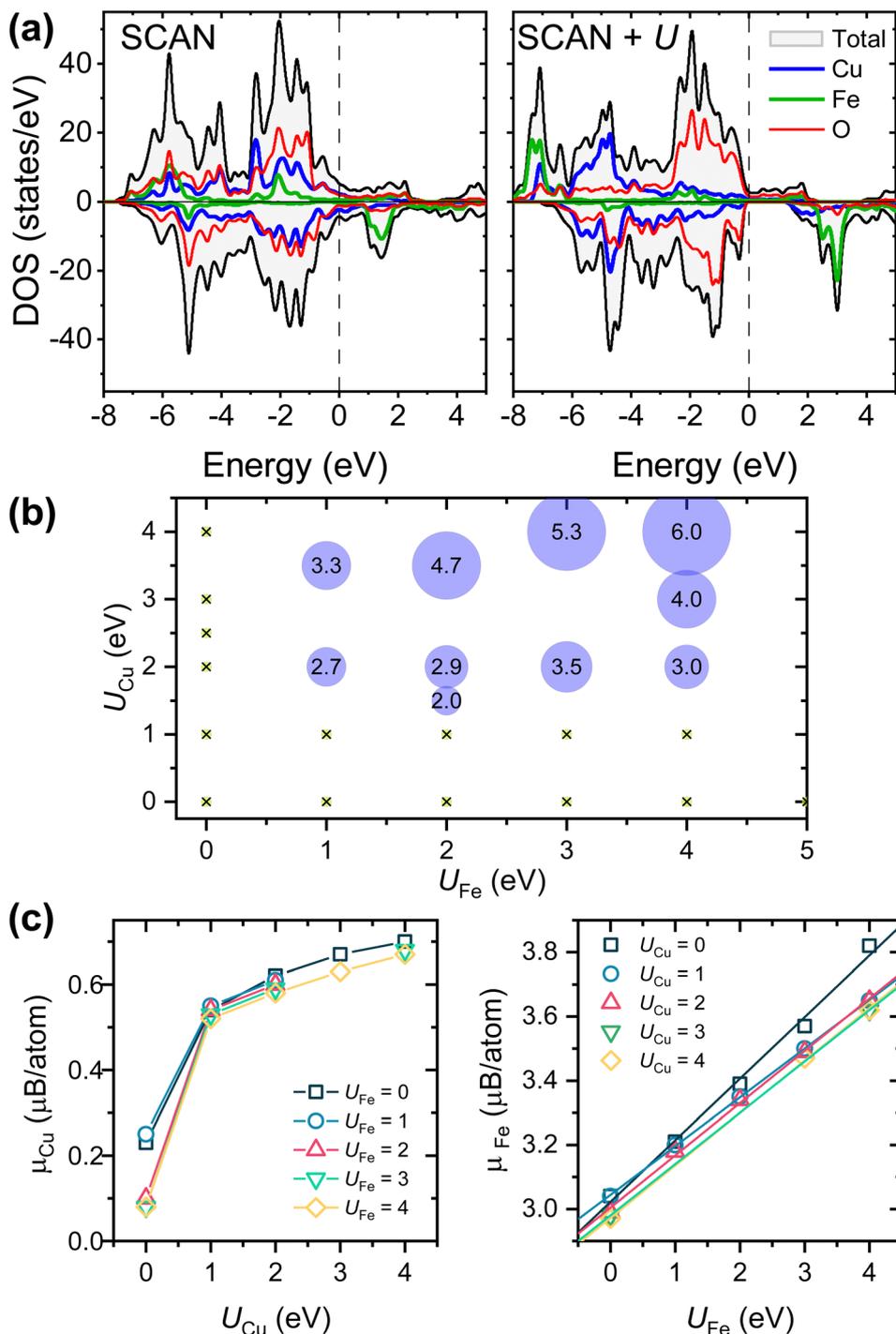


Fig. 3 (a) Calculated total and atom-projected density of states (DOS) for $YSr_2Cu_2FeO_8$ within the SCAN and SCAN+ U approximation ($U_{eff} = 4$ eV for Cu and Fe). The Fermi level is set as the zero of energy. DOS units refer to the calculated cell. Up spin (or majority) and down spin (or minority) contributions are shown. Color code: total black, Cu blue, Fe green, and O red. (b) Effect of the on-site Coulomb repulsion parameters U_{Fe} and U_{Cu} within the SCAN+ U approximation on the electronic properties of the $YSr_2Cu_2FeO_8$ idealized model. A metal (green dots) to half-metal (purple circles) transition occurs at $U_{Cu} \sim 2$ eV. For half-metallicity, the magnitude of the band gap in the down-spin channel is shown inside the purple circles. (c) Calculated local magnetic moments on Cu and Fe ions as a function of the U_{Fe} and U_{Cu} values employed in the SCAN+ U method.

(maximum 5 eV), the DOS corresponds to a metallic compound. For $U_{Cu} > 1.0$ eV and $U_{Fe} > 0$, an energy gap opens in the down spin channel, whose energy increases with larger U_{Fe} (see the band gap values in the circles). In addition to half-metallicity,

the introduction of the U parameter, and associated electron localization, produces increasing local magnetic moments (Fig. 3c) that deviate from the experimental observations, that is, $\mu_0(Fe) = 1.7\text{--}2$ μ_B per ion and $\mu_0(Cu) = 0$ μ_B .¹⁷ In this



regard, the introduction of the U term does not benefit property prediction.

Interestingly, as depicted in Fig. 3b and c, maintaining metallic characteristics in $\text{YSr}_2\text{Cu}_2\text{FeO}_8$ is possible with combinations such as $U_{\text{Cu}} = 0$ eV and $U_{\text{Fe}} = 5$ eV, as well as $U_{\text{Fe}} = 0$ and $U_{\text{Cu}} = 4$ eV. This is to say, electron localization does not occur when either U_{Cu} or U_{Fe} is set to zero. Fig. 4 reveals the impact of increasing only U_{Fe} or U_{Cu} , while keeping the other U -value

equal to zero. It can be inferred that since both Cu-3d and Fe-3d states contribute to the Fermi level, electron localization only occurs when both U -terms are greater than zero. Furthermore, the predominant contribution of Cu 3d-states at the Fermi level, characterized by a higher number of states compared to Fe 3d-states, results in U_{Cu} exerting a greater influence on the magnetic and electronic properties as well as on the Cu–O distances.

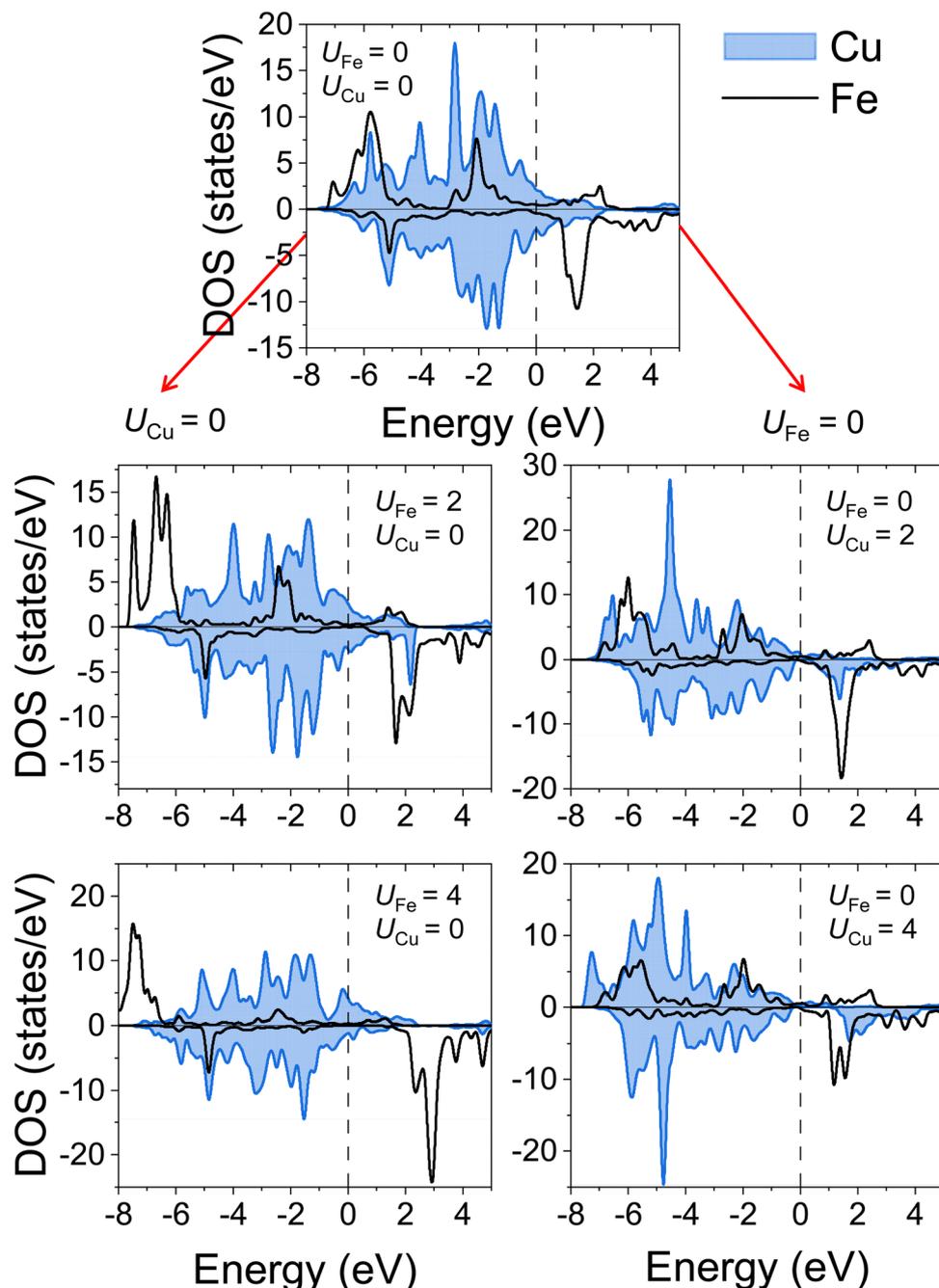


Fig. 4 Calculated atom-projected density of states for $\text{YSr}_2\text{Cu}_2\text{FeO}_8$ within the SCAN+ U approach. The evolution of the pDOS with U values for both TMs can be followed in columns. In the left column, U_{Cu} is set to zero and the metallic character is preserved independently of the U_{Fe} value. In the right column, U_{Fe} is set to zero, and increasing U_{Cu} drastically reduces the number of states at the Fermi level. The Fermi level is set as the zero of energy. Color code: Cu blue and Fe black.



Fig. 5a shows the calculated SCAN-DOS for the idealized model of C-type AFM-YSr₂Cu₂FeO₇. For this insulating oxide, the band gap extracted from diffuse reflectance spectroscopy (DRS) is in the range of 0.73–1.2 eV.⁸ As previously reported, the PBE+*U* (*U*_{Cu} and *U*_{Fe} = 4 eV) predicts a band gap of 0.85 eV, while the bare PBE fails to reproduce the insulating character of YSr₂Cu₂FeO₇. The SCAN functional yields a band gap of 0.63 eV, which widens when the *U* term is applied (SCAN+*U*). With *U* = 4 eV for Fe and Cu (Fig. 5a), the band gap is as wide as 2.3 eV. Fig. 5b unveils how the band gap can be tuned by the choice of the *U* values. Noteworthily, the band gap depends linearly on *U*_{Cu}, but it is almost insensitive to the choice of *U*_{Fe}, similarly with the afore-mentioned trend in the calculated Cu–O distances in this oxide. The experimental band gap is reproduced for 0 < *U*_{Cu} < 1 eV. For *U*_{Cu} = 0 eV, appropriate values of *U*_{Fe} range from 1 to

the maximum value tested (4 eV), whereas for *U*_{Cu} = 1 eV, any *U*_{Fe} value (including *U*_{Fe} = 0) yields the same band gap. Fig. 6 depicts the specific effects of *U*_{Cu} and *U*_{Fe} in the calculated DOS. While both, Cu and Fe-3d states, are significant parts of the top of the valence band, the bottom of the conduction band is formed exclusively by Cu-3d states. As *U*_{Cu} increases, these empty states shift up in energy, thereby opening the band gap.

Investigation of the hypothetical FM-YSr₂Cu₂FeO₇ supports the minor impact of *U*_{Fe} in property prediction. The calculated DOSs for the FM configuration (shown in Fig. 7a), indicate that within the SCAN+*U* approach, the *U* term drives the oxide from a metallic state (as described by the SCAN) to an insulating state. Fig. 7b shows the band gap opening as a function of the *U*_{Cu} and *U*_{Fe} values used in the calculations. In the same way as in the C-type AFM-YSr₂Cu₂FeO₇, the *U*_{Cu} dominates the band

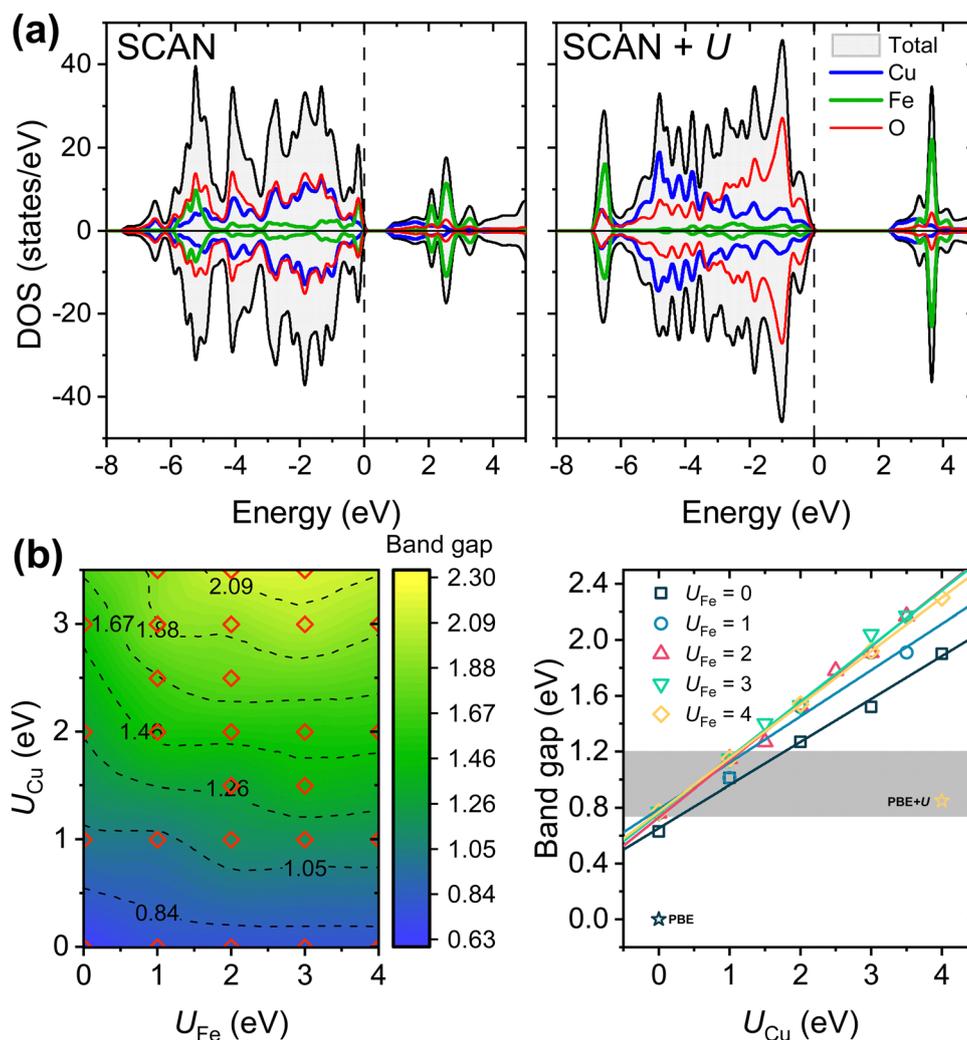


Fig. 5 (a) Calculated total and atom-projected density of states for YSr₂Cu₂FeO₇ in the C-type AFM configuration within the SCAN and SCAN+*U* approximation (*U*_{eff} = 4 eV for Cu and Fe). The Fermi level is set as the zero of energy. DOS units refer to the calculated cell. Up spin (or majority) and down spin (or minority) contributions are shown. Color code: total black, Cu blue, Fe green, and O red. (b) Dependence of the band gap for C-type AFM-YSr₂Cu₂FeO₇ with the *U* values on Fe and Cu utilized in the SCAN+*U* calculations. The experimental band gap is denoted by a gray region. The PBE (*U*_{Fe} and *U*_{Cu} = 0 eV) and PBE+*U* values (*U*_{Fe} and *U*_{Cu} = 4 eV) from a previous investigation⁸ are denoted by blue and yellow asterisks, respectively.



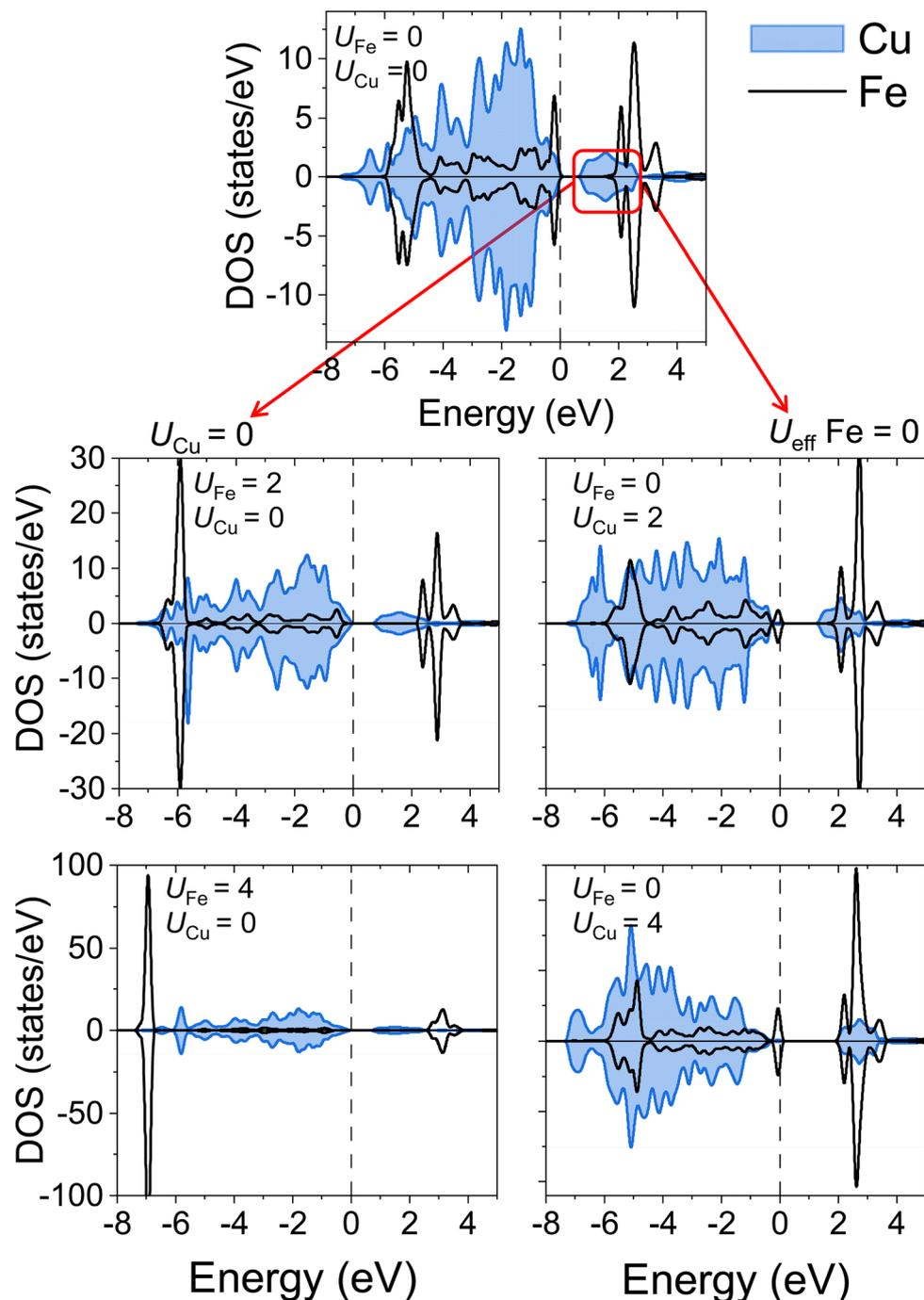


Fig. 6 Calculated atom-projected density of states for C-type AFM-YSr₂Cu₂FeO₇ within the SCAN+*U* methodology, showing the major impact of U_{Cu} on the electronic properties. The evolution of the pDOS with *U* values for both TMs can be followed in columns. In the left column, U_{Cu} is set to zero and the band gap value is preserved independently of the U_{Fe} value. In the right column, U_{Fe} is set to zero, and band gap widens with the increasing U_{Cu} values. Color code: Cu blue and Fe black.

gap opening, being the critical value $U = 2$ eV. In the insulating state, the magnitude of the band gap is nearly insensitive to U_{Fe} ; for instance, a band gap of 0.8 eV is obtained when $U_{\text{Cu}} = 4$ eV and U_{Fe} ranging from 0 to 4 eV. It should be noted that due to the lack of experimental data for FM-YSr₂Cu₂FeO₇, it is not conceivable to extract an optimal *U* value to model its properties. FM-YSr₂Cu₂FeO₇ is metastable relative to C-type

AFM under any DFT approximation, with energy differences per formula unit of 0.248 eV (PBE),⁸ 0.414 eV (SCAN),⁸ 0.424 eV (PBE+*U*, $U_{\text{Fe}} = U_{\text{Cu}} = 4$ eV),⁸ and 0.330 eV (SCAN+*U*, $U_{\text{Fe}} = U_{\text{Cu}} = 4$ eV). It is therefore unlikely that such a phase could ever be prepared.

The stabilization of the C-type AFM magnetic structure in insulating YSr₂Cu₂FeO₇ is attributed to local antiferromagnetic



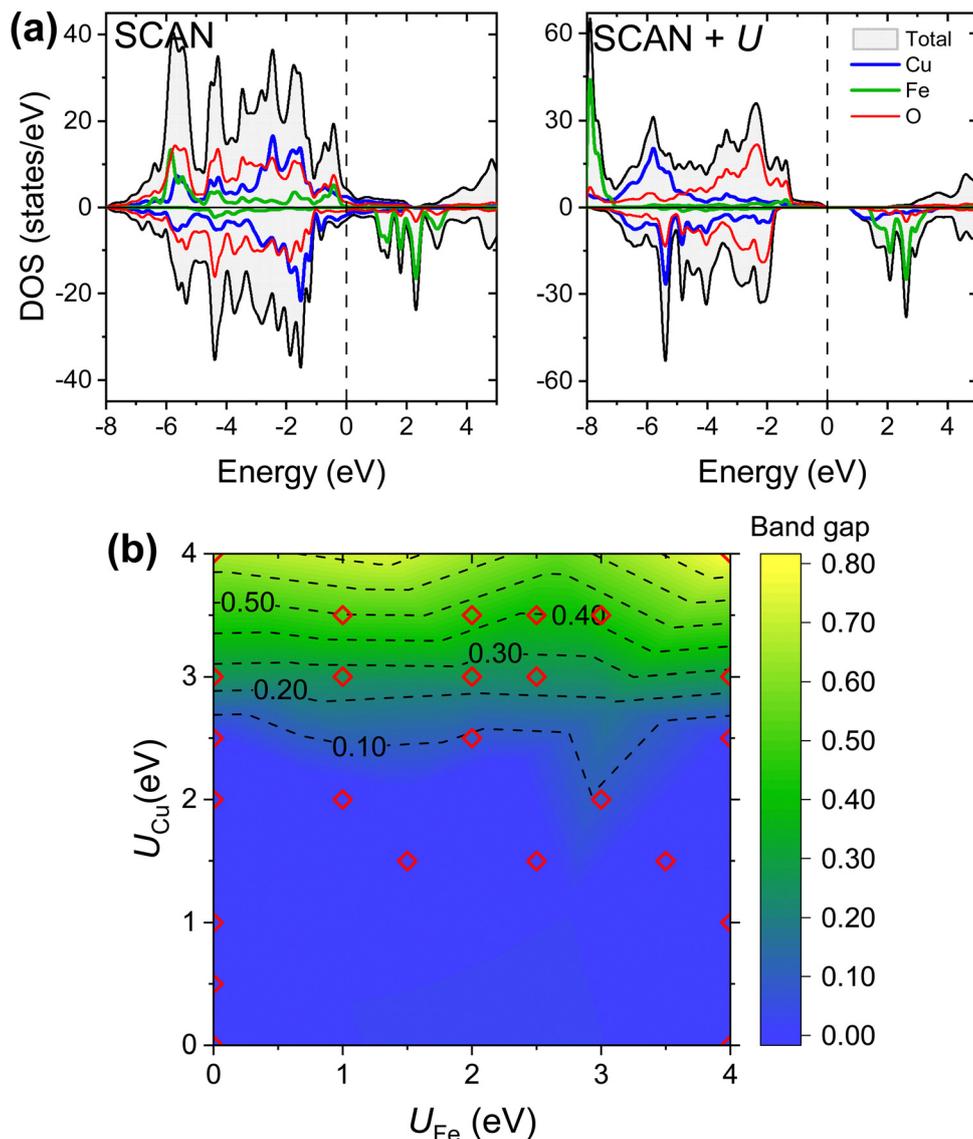


Fig. 7 (a) Calculated total and atom-projected density of states for $\text{YSr}_2\text{Cu}_2\text{FeO}_7$ in the FM configuration. The Fermi level is set as the zero of energy. DOS units refer to the calculated cell. Up spin (or majority) and down spin (or minority) contributions are shown. Color code: total black, Cu blue, Fe green, and O red. (b) FM- $\text{YSr}_2\text{Cu}_2\text{FeO}_7$ evolves from metallic (blue) to insulating behavior with increasing U_{Cu} values. The metal-to-insulator transition occurs at a critical U_{Cu} value of approximately 2.5 eV.

ordering within the Cu/Fe plane layer arising from superexchange interactions *via* oxygen bridges.^{8,34} In contrast, in-plane AFM ordering is not observed in the metallic $\text{YSr}_2\text{Cu}_2\text{FeO}_8$, for which an A-type AFM magnetic structure is reported.¹⁷ Noteworthy, the inter-plane magnetic interactions are weak throughout the $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ system.^{8,17,32,34} This is consistent with the small energy differences found between the inter-plane ferromagnetic and antiferromagnetic couplings in $\text{YSr}_2\text{Cu}_2\text{FeO}_7$ within the PBE, PBE+ U and SCAN approximations.⁸ For this oxide, the SCAN+ U ($U_{\text{Fe}} = U_{\text{Cu}} = 4$ eV) yields a negligible energy ($E_{\text{TotalFM}} - E_{\text{TotalA-AFM}}$) difference of 0.004 eV per formula unit. Similarly, for the metallic $\text{YSr}_2\text{Cu}_2\text{FeO}_8$, the A-type AFM configuration is only 0.018 eV per formula unit more stable than the FM configuration within the SCAN + U ($U_{\text{Fe}} = U_{\text{Cu}} = 4$ eV).

Discussion

The principal drawback of the DFT+ U schemes lies in the selection of the adjustable parameter, U . While U values can be derived from self-consistent calculations,³⁵ a common approach involves choosing these in order to match the experimental data, such as equilibrium volumes, formation energies, band gap values, transition pressures, intercalation voltages, and so on.^{10,25,26,36–38} It is impossible to pinpoint an exact and universally applicable value for the U parameter to accurately reproduce all material properties.³⁷ In this study, suitable ranges of U values are determined through comparison with experimental data on crystalline, magnetic and electronic structures.



The appropriate Hubbard U parameter varies depending on the nature and oxidation state of the transition metal (TM) as well as the crystal structure.²⁵ $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ ($\delta = 0, 1$) shares the same structural type, and for both compounds incorporating a U correction improves the reproduction of lattice parameters and Cu–O bond lengths. In the $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ system, the oxygen content determines the oxidation states of Cu and Fe as well as the magnetic interactions. For the magnetic structures, the SCAN+ U method performs equally well compared to the SCAN, PBE and PBE+ U methods: they all capture the occurrence of in-plane AFM ordering for $\delta \sim 0$, and the soft character of the inter-plane interactions throughout the $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ system. These DFT-trends, even when extracted from the idealized oxides with $\delta = 0$ and 1, are in good agreement with the observed magnetic properties of $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$.^{17,32,34}

The primary impact of U is observed in the electronic properties. In the metallic phase $\text{YSr}_2\text{Cu}_2\text{FeO}_8$, as expected, the U parameter penalizes electron delocalization, with $U_{\text{Cu}} > 1$ eV being detrimental for property prediction. On the other hand, for the insulating phase $\text{YSr}_2\text{Cu}_2\text{FeO}_7$, the electron correlation is better captured with $0 < U_{\text{Cu}} < 1$ eV and $U_{\text{Fe}} = 1\text{--}4$ eV. Considering these findings, the $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ system is better described with $U_{\text{Cu}} = 1$ eV, which improves the accuracy of the band gap for the insulating C-type AFM- $\text{YSr}_2\text{Cu}_2\text{FeO}_7$, while maintaining the metallic behavior of $\text{YSr}_2\text{Cu}_2\text{FeO}_8$. Importantly, once U_{Cu} is set to 1 eV, varying U_{Fe} between 0 and 4 eV has a minor impact on the calculated metal/insulating behavior of $\text{YSr}_2\text{Cu}_2\text{FeO}_8/\text{YSr}_2\text{Cu}_2\text{FeO}_7$ (Fig. 3b and 5b). The predominant role of U_{Cu} is consistent with the specific contributions of Cu-3d and Fe-3d states on the valence and conduction bands of $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$.

In the DFT+ U framework, there exists dependence of the appropriate U values on the XC-functional used. Despite the limited number of studies addressing the estimation of suitable U values within the SCAN+ U approach, a widespread observation is that the optimal U values for electronic property prediction are notably lower than those within the PBE+ U method.^{9,12,27} This remark is supported by comparing the current SCAN+ U results for $\text{YSr}_2\text{Cu}_2\text{FeO}_7$ with a previous investigation using PBE+ U (Fig. 5b).⁸ In the PBE+ U approach, applying U_{eff} values of ~ 4 eV for Cu and Fe ions, a calculated band gap of 0.85 eV is achieved, which falls in the experimental range. However, using the same U values in the SCAN+ U method significantly overestimates the band gap, widening it to 2.3 eV. Fig. 2 and 5b suggest that the calculated bonding distances and band gaps exhibit a linear trend with the U value, displaying similar slopes for both SCAN+ U and PBE+ U methods. Since the bare PBE and SCAN produce different values (either for band gaps or bond-lengths), the optimal U values matching the experimental data definitely depend on the chosen XC functional.

Finally, within the SCAN+ U method, the optimal U values for modelling the $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ compounds can be compared to those previously reported for the simple Fe and Cu oxides. Previous studies have suggested that the optimal U_{Fe} value is around ~ 3 eV for $\text{FeO}/\text{Fe}_2\text{O}_3/\text{Fe}_3\text{O}_4$ ⁹ and BiFeO_3 .¹² Carter *et al.*

demonstrated that, while SCAN is sufficient to reproduce the crystal structure and formation energies of CuO and Cu_2O , the proper simulation of the electronic structure requires the introduction of U_{Cu} at around ~ 2 eV.¹⁰ However, applying the combination extracted from simple oxides ($U_{\text{Cu}} = 2$ eV and $U_{\text{Fe}} = 3$ eV), a poor description of the electronic properties of the $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ system is given. This combination leads to a half-metallic behavior (and electron localization) for $\text{YSr}_2\text{Cu}_2\text{FeO}_8$, and band gaps that deviate from the experimental values for $\text{YSr}_2\text{Cu}_2\text{FeO}_7$. In short, the appropriate U parameters found for the simple Cu/Fe oxides are not suitable for reproducing the properties of the complex oxides $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$. The differences between the optimal U -values for simple and complex TM oxides are linked to the specific contributions of the TM-d states in the electronic structure.

Conclusions

The SCAN functional effectively models the crystal structure and basic electronic and magnetic properties of complex oxides $\text{YSr}_2\text{Cu}_2\text{FeO}_{7+\delta}$ ($0 < \delta < 1$). Although adding a U correction on top is not necessary, it is found that applying a U_{Cu} value of 1 eV leads to a more accurate description of properties. In this case study, the Cu-3d states dominate, respectively, the Fermi level of $\text{YSr}_2\text{Cu}_2\text{FeO}_8$ and the bottom of the conduction band of $\text{YSr}_2\text{Cu}_2\text{FeO}_7$. Consequently, U_{Cu} has a greater impact than U_{Fe} in the calculated electronic properties and magnetic moments. Indeed, for a fixed U_{Cu} , the results are almost insensitive to U_{Fe} .

This case study highlights the importance of analyzing the role of the individual U parameters for the reliable SCAN+ U investigations of complex oxides containing several TM ions. The optimal U -values certainly depend on the material under investigation (chemical composition and crystal structure), and U -transferability among materials is particularly risky for such complex oxides. The appropriate combination of U_{TM} terms may differ from the optimal values in the respective simple oxides. Therefore, the convenience of using the SCAN+ U approach in the study of oxides containing several TM ions should be assessed for each material, considering whether the benefits in property prediction (compared to the SCAN functional) outweigh the efforts made in determining the optimal combination of individual U_{TM} values.

Author contributions

Mariela Gómez-Toledo: investigation, methodology, software, data curation, validation, formal analysis, visualization, and writing – original draft. Elena M. Arroyo-de Dompablo: investigation, conceptualization, supervision, funding acquisition, project administration, and writing – original draft.

Conflicts of interest

There are no conflicts to declare.



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